

9W 940nm High Power Single Emitter Laser Diode on Submount SES9-940-01

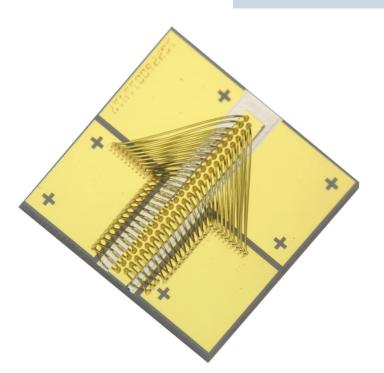
The Bookham SES9-940-01 single emitter laser diode series has been designed to provide the high output power, high coupling efficiency and high reliability required for pumping next generation fiber lasers and for other high power laser diode applications. The proprietary E2 front mirror passivation process, developed at our Zurich site, prevents Catastrophic Optical Damage (COD) to the laser diode facet even at extremely high output powers. The single emitter laser diodes are p-side down mounted on an optimized submount providing very low thermal resistance.

Features:

- 3.6mm x 0.4mm laser diode
- 90µm wide emitter
- 9W operating power (p-side down mounted)
- Highly reliable single quantum well MBE structure
- Standard wavelength at 940nm (other available on request)
- RoHS compliant

Applications:

- Fiber laser pumping
- Material processing
- Printing
- Medical





Characteristics

| Parameter | Symbol | Typical | Unit |
|---|--|----------|-------|
| CW Output Power | P _{op} | 9 | W |
| Center Wavelength [1] | λ_{c} | 940 ± 10 | nm |
| Spectral Width (FWHM) | Δλ | 4 | nm |
| Wavelength Shift with Temperature | $d\lambda_c/dT_{op}$ | 0.3 | nm/°C |
| Beam Divergence (FWHM) Parallel to Junction Perpendicular to Junction | $\theta_{/\prime} \\ \theta_{\perp}$ | 8 29 | deg |
| Polarization | - | TE | - |
| Threshold Current | l _{th} | 500 | mA |
| Slope Efficiency | $\eta_D = P_{op} / (I_{op} - I_{th})$ | 1.0 | W/A |
| Conversion Efficiency | H=P _{op} /(V _{op} xI _{op}) | > 50 | % |
| Series Resistance | R _s | 0.03 | Ω |
| Operating Current | I _{op} | 9.5 | A |
| Operating Voltage | V _{op} | 2.2 | V |
| Operating Temperature | T _{op} | 25 ± 5 | °C |

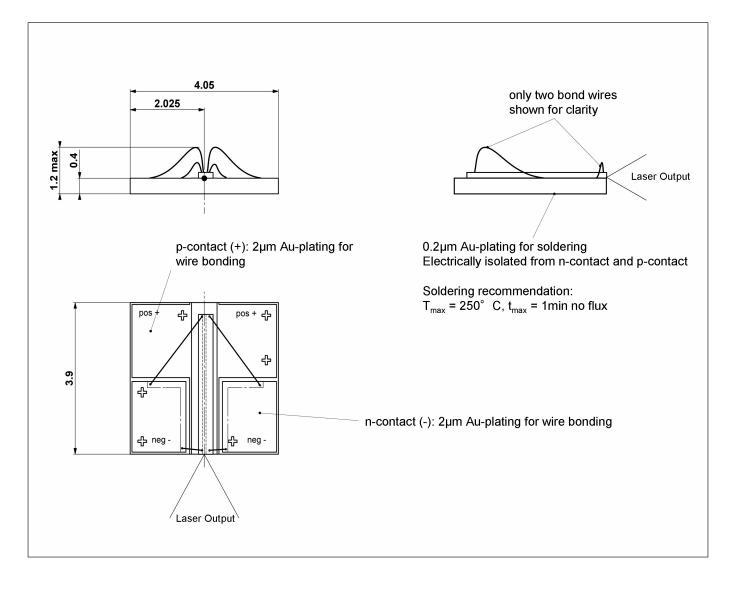
[1] Reduced wavelength window/extended range available on request (900-1070nm).

Chip Dimensions

| Parameter | Symbol | Typical | Unit |
|------------------|--------|---------|------|
| Chip Width | b | 400 | μm |
| Resonator Length | I | 3600 | μm |
| Chip Thickness | d | 150 | μm |
| Emitter Width | W | 90 | μm |



Package Dimensions (mm)





RoHS Compliance 💋



Bookham is fully committed to environment protection and sustainable development and has set in place a comprehensive program for removing polluting and hazardous substances from all of its products. The relevant evidence of RoHS compliance is held as part of our controlled documentation for each of our compliant products. RoHS compliance parts are available to order, please refer to the ordering information section for further details.

Ordering Information:

SES9-940-01

9W 940nm Single Emitter Laser Diode on Submount

Contact Information

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